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	1	S	Sheet 1	of <u>1</u>		
of Commerce RK OFFICE	136081	OOCKET NO.		APPLICATION NO. 10/556,063		
	A PPI IC	ANT(S)				
		shi TAKAHASHI et al.				
		DATE 0, 2007	GROUP 1753			
U.S. PATEN	T DOCUM	1ENTS				
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FOREIGN PAT	ENT DOC	UMENTS		1		
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	DOCUME					
CAPITAL LET og, etc.), date, p	TERS), tit page(s), vol	le of the article (when appropriate), title lume-issue number(s), publisher, city and	of the item (book l/or country wher	, magazine, e published.		
		d-Through Silicon Nitride Rear Contacts				

OTHER DOCUMENTS									
Examiner Initials	Cite No.	Including name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.							
	1	B. LENKEIT et al., "High Quality Screen-Printed and Fired-Through Silicon Nitride Rear Contacts for Bifacial Silicon Sc Cells," PROCEEDINGS OF THE INTERNATIONAL PHOTOVOLTAIC SOLAR ENERGY CONFERENCE, May 1, 200 pages 1332-1335, XP-001138888, London							
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